

Abstracts

4-8 GHz High Power Cascadable Packaged GaAs FET Amplifier

S. Yamamura, M. Shigaki, N. Hidaka, H. Ishikawa, M. Takase and M. Fukuta. "4-8 GHz High Power Cascadable Packaged GaAs FET Amplifier." 1981 MTT-S International Microwave Symposium Digest 81.1 (1981 [MWSYM]): 123-125.

A 4-8 GHz 1 W GaAs FET amplifier module in a 6 x 16 x 3.5 mm ceramic package with 6 terminals has been developed. The modules can be directly cascaded quite easily since they have standardized interfaces.

 [Return to main document.](#)